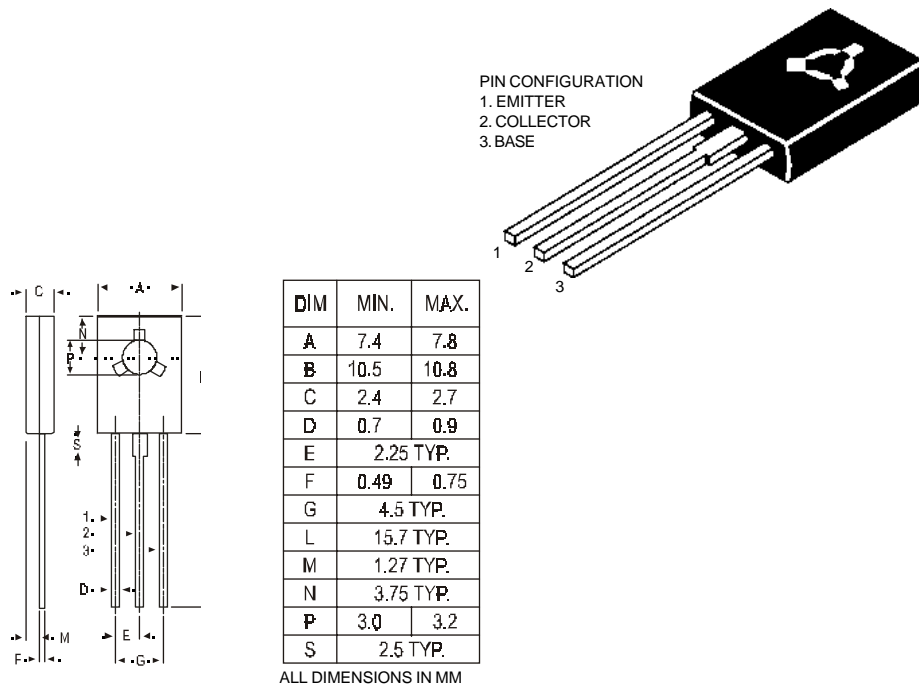


TO-126 (SOT-32) Plastic Package

BD166, BD168, BD170

BD166, 168, 170 PNP PLASTIC POWER TRANSISTORS
 Complementary BD165, 167, 169
 Audio Amplifier and Driver Circuit Applications



ABSOLUTE MAXIMUM RATINGS

		166	168	170	
Collector-base voltage (open emitter)	V_{CB0}	max. 45	60	80	V
Collector-emitter voltage (open base)	V_{CEO}	max. 45	60	80	V
Collector current	I_C	max. 1.5			A
Total power dissipation up to $T_C = 25^\circ\text{C}$	P_{tot}	max. 20			W
Junction temperature	T_j	max. 150			$^\circ\text{C}$
Collector-emitter saturation voltage $I_C = 0.5\text{ A}; I_B = 0.05\text{ A}$	V_{CEsat}	max. 0.5			V
D.C. current gain $I_C = 0.15\text{ A}; V_{CE} = 2\text{ V}$	h_{FE}	min. 40			

RATINGS (at $T_A=25^\circ\text{C}$ unless otherwise specified)

Limiting values		166	168	170	
Collector-base voltage (open emitter)	V_{CB0}	max. 45	60	80	V
Collector-emitter voltage (open base)	V_{CEO}	max. 45	60	80	V
Emitter-base voltage (open collector)	V_{EBO}	max. 5.0			V

BD166, BD168, BD170

Collector current	I_C	max.	1.5	A
Base current	I_B	max.	0.5	A
Total power dissipation up to $T_A = 25^\circ\text{C}$	P_{tot}	max.	1.25	W
Derate above 25°C		max	10	mW/°C
Total power dissipation up to $T_C = 25^\circ\text{C}$	P_{tot}	max.	20	W
Derate above 25°C		max	160	mW/°C
Junction temperature	T_j	max.	150	°C
Storage temperature	T_{stg}		-65 to +150	°C

THERMAL RESISTANCE

From junction to case	$R_{th\ jc}$	6.25	°C/W
From junction to ambient	$R_{th\ ja}$	100	°C/W

CHARACTERISTICS

$T_{amb} = 25^\circ\text{C}$ unless otherwise specified

		166	168	170	
Collector cutoff current					
$I_E = 0; V_{CB} = 45\text{ V}$	I_{CBO}	max. 0.1	–	–	mA
$I_E = 0; V_{CB} = 60\text{ V}$	I_{CBO}	max. –	0.1	–	mA
$I_E = 0; V_{CB} = 80\text{ V}$	I_{CBO}	max. –	–	0.1	mA
Emitter cut-off current					
$I_C = 0; V_{EB} = 5\text{ V}$	I_{EBO}	max.	1.0		mA
Breakdown voltages					
$I_C = 0.1\text{ A}; I_B = 0$	$V_{CEO(sus)}^*$	min. 45	60	80	V
$I_C = 1\text{ mA}; I_E = 0$	V_{CBO}	min. 45	60	80	V
$I_E = 1\text{ mA}; I_C = 0$	V_{EBO}	min.	5.0		V
Saturation voltage					
$I_C = 0.5\text{ A}; I_B = 0.05\text{ A}$	V_{CEsat}^*	max.	0.5		V
Base-emitter on voltage					
$I_C = 0.5\text{ A}; V_{CE} = 2\text{ V}$	$V_{BE(on)}^*$	max.	0.95		V
D.C. current gain					
$I_C = 0.15\text{ A}; V_{CE} = 2\text{ V}$	h_{FE}^*	min.	40		
$I_C = 0.5\text{ A}; V_{CE} = 2\text{ V}$	h_{FE}^*	min.	15		
Transition frequency $f = 1\text{ MHz}$					
$I_C = 500\text{ mA}; V_{CE} = 2\text{ V}$	f_T	min.	6.0		MHz

* Pulse test: pulse width $\leq 300\ \mu\text{s}$; duty cycle $\leq 2\%$.

Notes

Disclaimer

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